

2ch VOLTAGE DETECTOR

■ GENERAL DESCRIPTION

The NJU7712/13 is a 2ch low quiescent current voltage detector featuring high precision detection voltage.

The detection voltage is fixed internally with an accuracy of 1.0%.

NJU7712 is Nch. Open Drain and NJU7713 of output circuit form is a C-MOS output.

■ PACKAGE OUTLINE

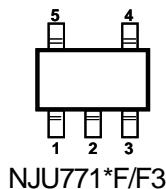


NJU7712/13F NJU7712/13F3

■ FEATURES

● High Precision detection Voltage	$\pm 1.0\%$
● Low Quiescent Current	$0.8\mu A$ (per 1ch)
● Detection Voltage Range	1.5 ~ 6.0V(0.1V step) It applies only to 1ch(Over Voltage Detect). 1.3 ~ 6.0V(0.1V step) It applies only to 2ch(Low Voltage Detect).
● 1ch: Over Voltage Detect, 2ch: Low Voltage Detect	
● Output Circuit Form	NJU7712: Nch. Open Drain Type NJU7713: C-MOS Output Type
● CMOS Technology	
● Package Outline	SOT-23-5 (MTP5) / SC88A

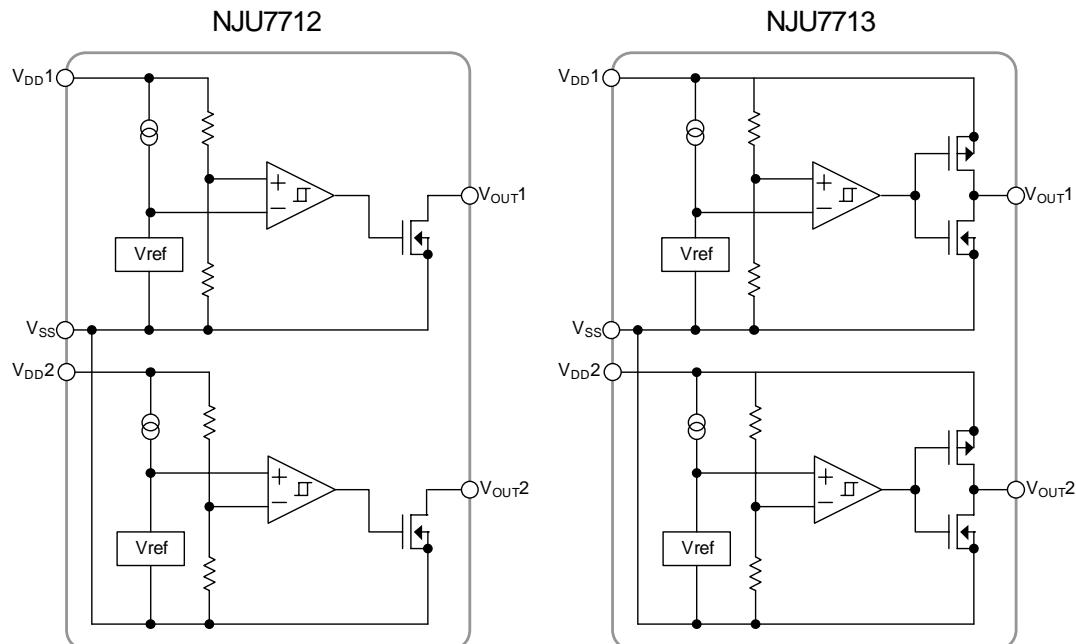
■ PIN CONFIGURATION



PIN FUNCTION

- 1. V_{OUT1}
- 2. V_{SS}
- 3. V_{DD1}
- 4. V_{DD2}
- 5. V_{OUT2}

■ EQUIVALENT CIRCUIT



NJU7712/13

■ DETECTION VOLTAGE RANK LIST

Device Name	Package	V_{DET}	
		CH1	CH2
NJU7712/13F4227	SOT-23-5 (MTP5)	4.2V	2.7V
NJU7712/13F0613		6.0V	1.3V
NJU7712/13F3-4227	SC88A	4.2V	2.7V
NJU7712/13F3-0613		6.0V	1.3V

■ NJU7712

■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Input Voltage	V _{DD}	+10	V
Output Voltage	V _{OUT}	V _{SS} -0.3 ~ +10	V
Output Current	I _{OUT}	50	mA
Power Dissipation	P _D	200(MTP5) 250(SC88A(*note 1))	mW
Operating Temperature	T _{opr}	-40 ~ +85	°C
Storage Temperature	T _{stg}	-40 ~ +125	°C

(*note 1): On board, 50mm×50mm×1.6mm glass epoxy baseplate.

■ ELECTRICAL CHARACTERISTICS

(1ch: Over Voltage Detect, Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION		MIN.	TYP.	MAX.	UNIT
Detection Voltage	V _{DET1}			-1.0%	—	+1.0%	V
Hysteresis Voltage	V _{HYS1}			V _{DET} ×0.03	V _{DET} ×0.05	V _{DET} ×0.08	V
Quiescent Current	I _{ss1}	V _{DD1} =V _{DET1} +1V	V _{DET1} =1.5V ~ 1.7V Version V _{DET1} =1.8V ~ 6.0V Version	—	0.5	1.0	μA
Output Current	I _{OUT1}	Nch, V _{DS1} =0.5V	V _{DD1} =4.8V(≤4.3V Version) V _{DD1} =7.0V	6	13	—	mA
Output Leak Current	I _{LEAK1}	V _{DD1} =V _{OUT1} =9V		—	—	0.1	μA
Detection Voltage Temperature Coefficient	ΔV _{DET1} /ΔTa	Ta=0 ~ +85°C		—	±100	—	ppm/°C
Operating Voltage (*note 2)	V _{DD1}	R _{L1} =100kΩ		0.8	—	9	V

(*note 2): The minimum Operating Voltage(V_{OPL}) indicates the same value of the output voltage(V_{OUT}) on condition that V_{OUT} becomes 90% or less of the input voltage(V_{DD}).

(2ch: Low Voltage Detect, Ta=25°C)

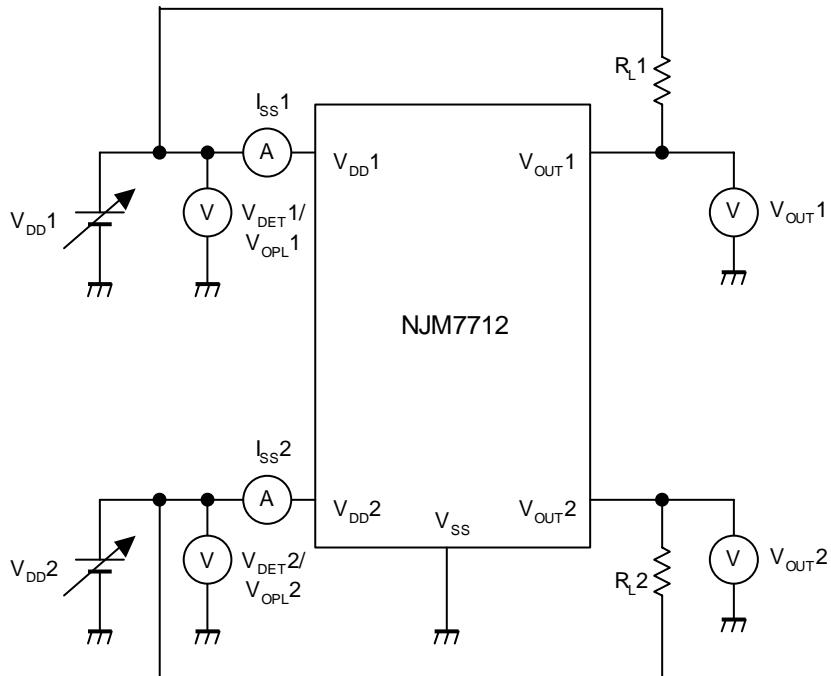
PARAMETER	SYMBOL	TEST CONDITION		MIN.	TYP.	MAX.	UNIT
Detection Voltage	V _{DET2}			-1.0%	—	+1.0%	V
Hysteresis Voltage	V _{HYS2}			V _{DET} ×0.03	V _{DET} ×0.05	V _{DET} ×0.08	V
Quiescent Current	I _{ss2}	V _{DD2} =V _{DET2} +1V	V _{DET2} =1.3V ~ 1.7V Version V _{DET2} =1.8V ~ 6.0V Version	—	0.5	1.0	μA
Output Current	I _{OUT2}	Nch, V _{DS2} =0.5V	V _{DD2} =1.2V V _{DD2} =2.4V (≥4.3V Version)	0.75	2.0	—	mA
Output Leak Current	I _{LEAK2}	V _{DD2} =V _{OUT2} =9V		—	—	0.1	μA
Detection Voltage Temperature Coefficient	ΔV _{DET2} /ΔTa	Ta=0 ~ +85°C		—	±100	—	ppm/°C
Operating Voltage (*note 3)	V _{DD2}	R _{L2} =100kΩ		0.8	—	9	V

(*note 3): The minimum Operating Voltage(V_{OPL}) indicates the same value of the output voltage(V_{OUT}) on condition that V_{OUT} becomes 10% or less of the input voltage(V_{DD}).

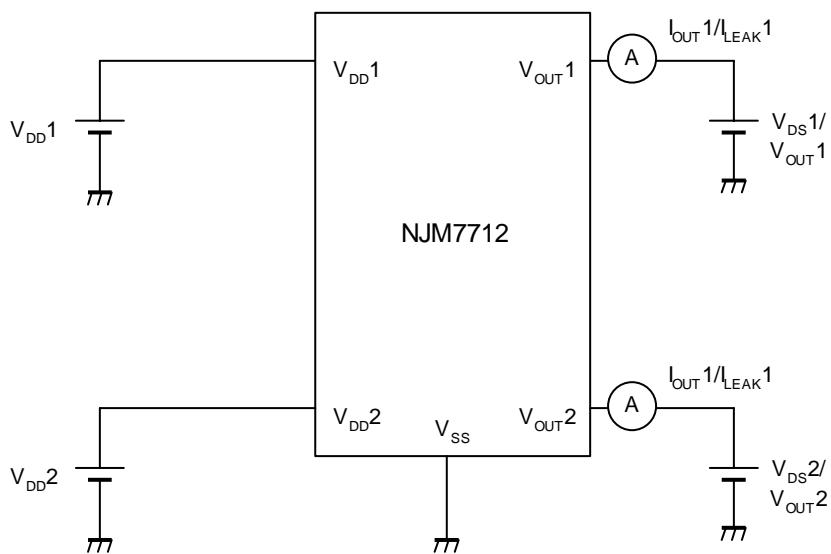
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■ TEST CIRCUIT

① COMMON TEST CIRCUIT

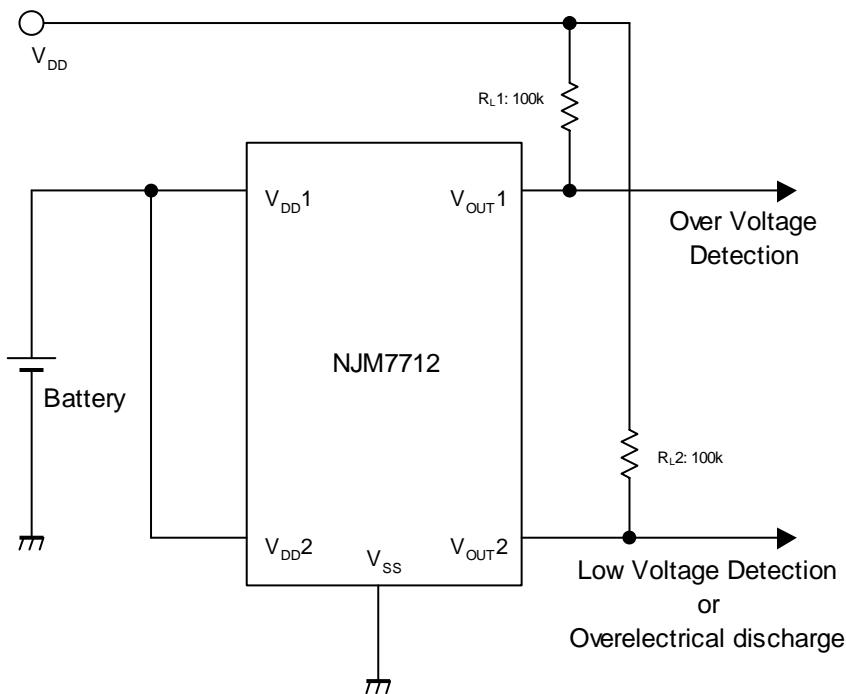


② OUTPUT CURRENT / LEAK CURRENT TEST CIRCUIT

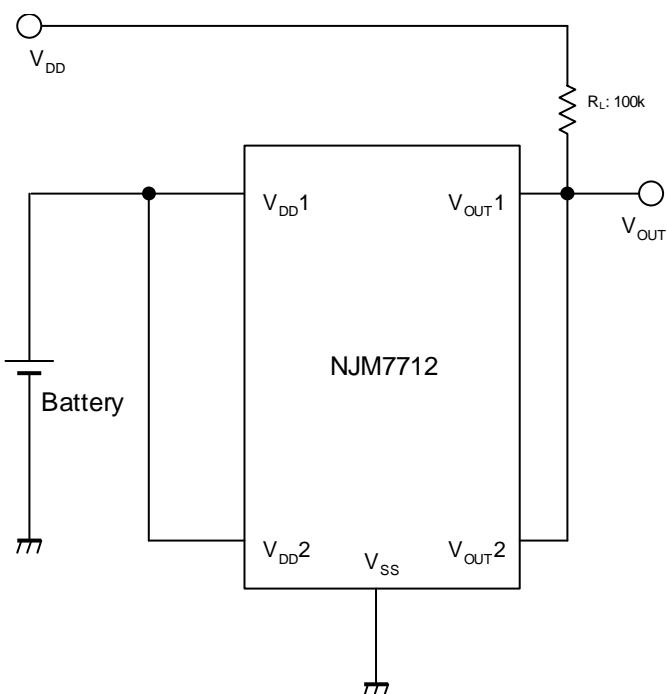


■ TYPICAL APPLICATION

① Battery voltage supervision



② Window Comparator



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■ NJU7713

■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Input Voltage	V _{DD}	+10	V
Output Voltage	V _{OUT}	V _{SS} -0.3 ~ +10	V
Output Current	I _{OUT}	50	mA
Power Dissipation	P _D	200(MTP5) 250(SC88A(*note 1))	mW
Operating Temperature	T _{opr}	-40 ~ +85	°C
Storage Temperature	T _{stg}	-40 ~ +125	°C

(*note 1): On board, 50mm×50mm×1.6mm glass epoxy baseplate.

■ ELECTRICAL CHARACTERISTICS

(1ch: Over Voltage Detect, Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION		MIN.	TYP.	MAX.	UNIT
Detection Voltage	V _{DET1}			-1.0%	—	+1.0%	V
Hysteresis Voltage	V _{HYS1}			V _{DET} x0.03	V _{DET} x0.05	V _{DET} x0.08	V
Quiescent Current	I _{ss1}	V _{DD1} =V _{DET1} +1V	V _{DET1} =1.5V ~ 1.7V Version V _{DET1} =1.8V ~ 6.0V Version	—	0.5	1.0	μA
Output Current	I _{OUT1}	Nch, V _{DS1} =0.5V	V _{DD1} =4.8V(≤4.3V Version)	6	13	—	mA
			V _{DD1} =7.0V	8	18	—	mA
		Pch, V _{DS1} =0.5V	V _{DD1} =1.4V	0.1	0.4	—	mA
			V _{DD1} =2.4V(≥2.7V Version)	0.6	1.6	—	mA
Detection Voltage Temperature Coefficient	ΔV _{DET1} /ΔTa	Ta=0 ~ +85°C		—	±100	—	ppm/°C
Operating Voltage (*note 4)	V _{DD1}	R _{L1} =100kΩ		1.2	—	9	V

(*note 4): The minimum Operating Voltage(V_{OPL}) indicates the same value of the output voltage(V_{OUT}) on condition that V_{OUT} becomes 90% or less of the input voltage(V_{DD}).

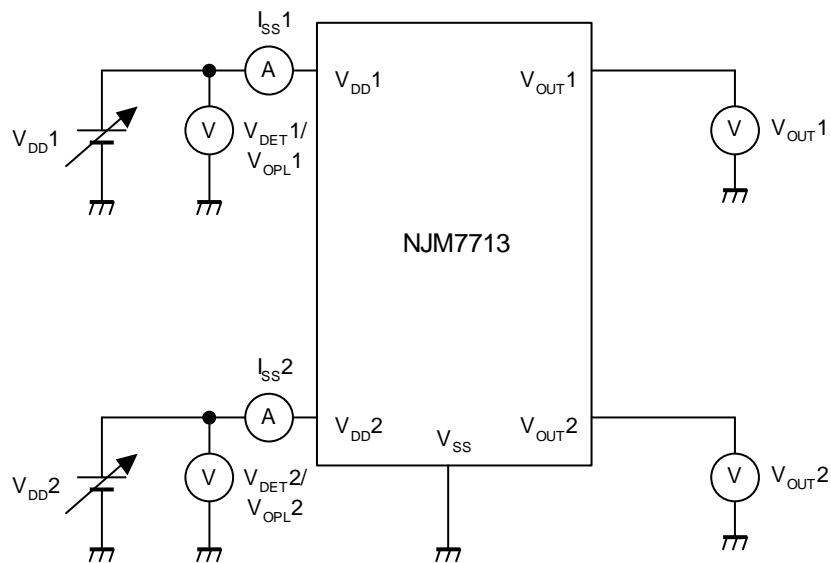
(2ch: Low Voltage detect, Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION		MIN.	TYP.	MAX.	UNIT
Detection Voltage	V _{DET2}			-1.0%	—	+1.0%	V
Hysteresis Voltage	V _{HYS2}			V _{DET} x0.03	V _{DET} x0.05	V _{DET} x0.08	V
Quiescent Current	I _{ss2}	V _{DD2} =V _{DET2} +1V	V _{DET2} =1.5V ~ 1.7V Version V _{DET2} =1.8V ~ 6.0V Version	—	0.5	1.0	μA
Output Current	I _{OUT2}	Nch, V _{DS2} =0.5V	V _{DD2} =4.8V(≤4.3V Version)	0.75	2.0	—	mA
			V _{DD2} =7.0V	4.5	7.0	—	mA
			Pch, V _{DS2} =0.5V	V _{DD2} =1.4V	2.0	3.5	—
V _{DD2} =2.4V (4.0V~5.6V Version)	2.5	4.0		—	mA		
			V _{DD2} =8.4V (≥5.7V Version)	3.0	5.0	—	mA
Detection Voltage Temperature Coefficient	ΔV _{DET2} /ΔTa	Ta=0 ~ +85°C		—	±100	—	ppm/°C
Operating Voltage (*note 5)	V _{DD2}	R _{L2} =100kΩ		0.8	—	9	V

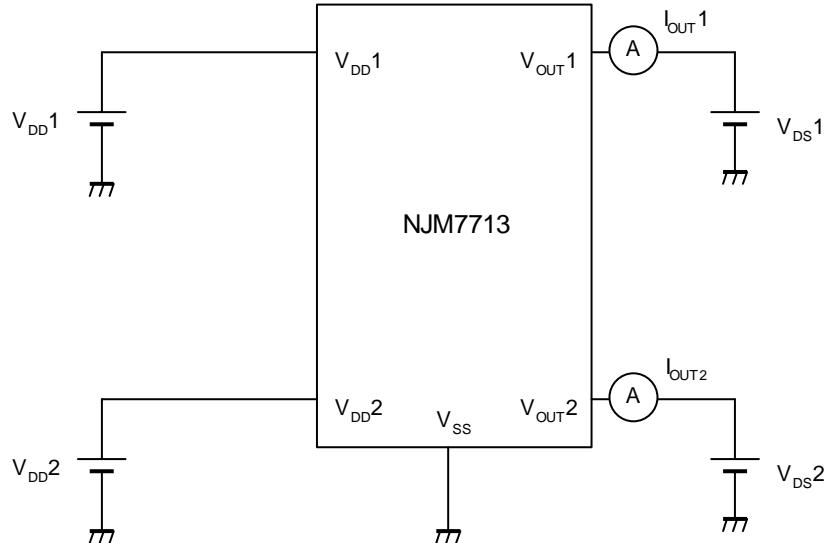
(*note 5): The minimum Operating Voltage(V_{OPL}) indicates the same value of the output voltage(V_{OUT}) on condition that V_{OUT} becomes 10% or less of the input voltage(V_{DD}).

■ TEST CIRCUIT

① COMMON TEST CIRCUIT

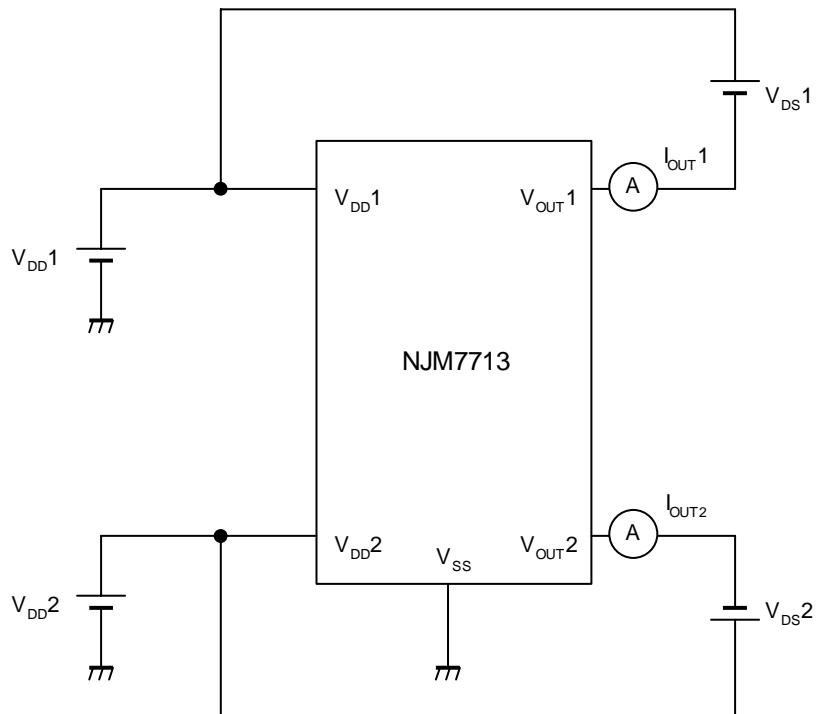


② Nch OUTPUT CURRENT TEST CIRCUIT

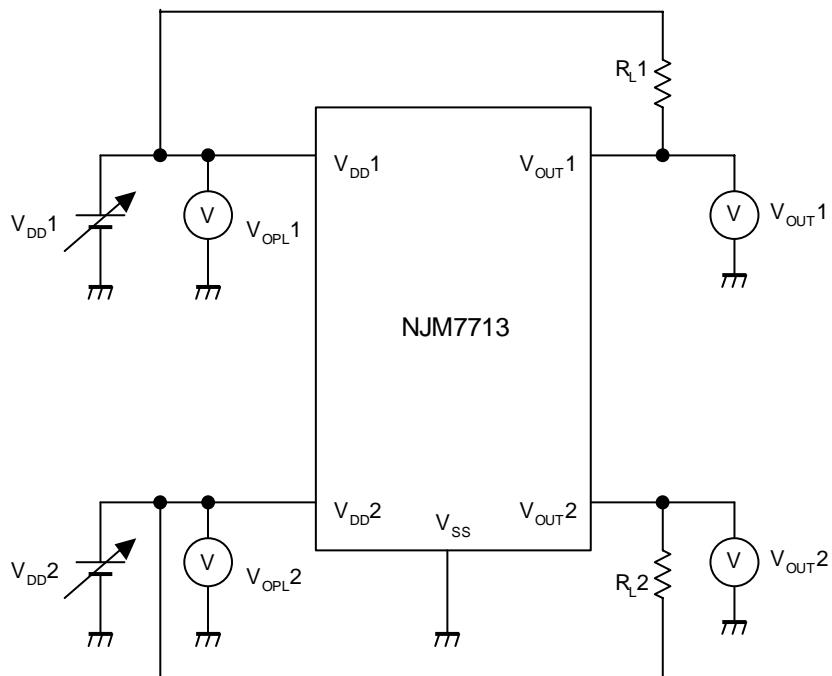


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③ Pch OUTPUT CURRENT TEST CIRCUIT

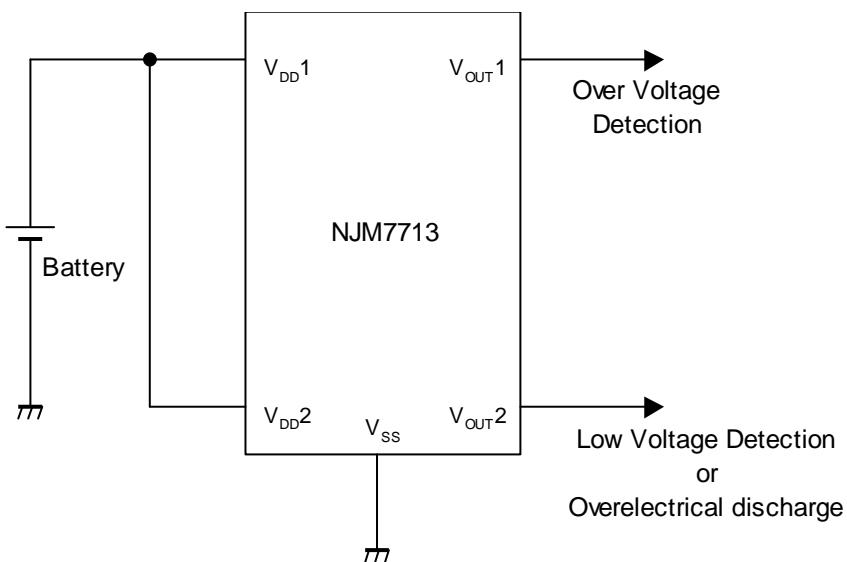


④ MINIMUM OPERATING VOLTAGE TEST CIRCUIT



■ TYPICAL APPLICATION

- ① Battery voltage supervision



[CAUTION]

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